



2.0 GHz PLL Frequency Synthesizer IC

Preliminary

Overview

The SANYO LV2151V is a 2.0 GHz PLL frequency synthesizer IC that features low-voltage operation and low current drain and is suitable for CATV, DAB, and mobile phone systems.

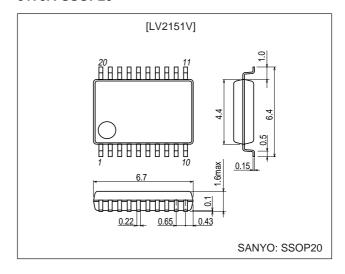
Features

- A wide range of operating frequency from 0.2 to 2.0 GHz
- I²C bus/ 3-wire bus selective. (For I²C bus WRITE mode only)
- Includes three ports for band switch
- Includes unlock detect indicator.
- · Battery saving mode
- 2.7V to 3.5 V operation
- Small package 20-pin SSOP (Lead pitch 0.65mm)

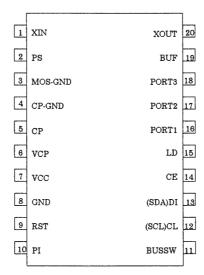
Package Dimensions

unit: mm

3179A-SSOP20



Pin Assignment



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Specifications

Absolute Maximum Ratings at $Ta = 25^{\circ}C$

Parameter	Symbol	Pin	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max	V _{CC} , VCP		4.5	V
Maximum input voltage	Vin max	SCL(CL), SDA(DI) CE, PS, RST, BUSSW		-0.3 to V _{CC} + 0.3	V
Maximum output voltage	Vout max	LD, PORT1 to 3, SDA(DI)		-0.3 to $V_{CC} + 0.3$	V
Maximum output current1	I _{OUT} max1	PORT1 to 3, SDA(DI)		4	mA
Maximum output current2	I _{OUT} max2	LD		0.7	mA
Allowable power dissipation	Pd max		Ta ≤ 85°C	50	mW
Operating temperature	Topr			-30 to +85	°C
Storage temperature	Tstg			-50 to +125	°C

Operating Conditions at $Ta = 25^{\circ}C$

Parameter	Symbol	Pin		Ratings		Unit
Falametei	Symbol	F""	min	typ	max	Offic
Recommended power supply voltage	V _{CC}	V _{CC} , VCP		3.0		V
Operating voltage range	V _{CCOP}	V _{CC} , VCP	2.7		3.5	V

Allowable Operating Ranges at $Ta = -30 \text{ to } +85^{\circ}\text{C}$

Parameter	O. mala al	Pin	Conditions		Ratings		Unit
Parameter	Symbol	Pin	Conditions	min	typ	max	Unit
Supply voltage	Vcc	V _{CC} , VCP		2.7		3.5	V
High-level input voltage	V _{IH}	SCL(CL), SDA(DI), CE, PS, RST, BUSSW		V _{CC} *0.7		Vcc	V
Low-level input voltage	V _{IL}	SCL(CL), SDA(DI), CE, PS, RST, BUSSW		0		0.6	٧
Input frequency	fin(1)	XIN	AC Coupled	4		22	MHz
	fin(2)	PI	*	0.2		2.0	GHz
Input amplitude	Vin(1)	XIN	AC Coupled	-12		10	dBm
	Vin(2)	PI	*	-12		0	dBm
Guaranteed crystal oscillation	Xtal	XIN, XOUT		4		22	MHz

Note: *50 Ω terminate (0 dBm = 0.224 Vrms)

Electrical Characteristics at $Ta=25^{\circ}C,\,V_{CC}=3.0~V$

Parameter	Oh - I	Pin	Conditions		Ratings		Unit
Parameter	Symbol	Pin	Conditions	min	typ	max	Onit
Low-level output voltage1	V _O L1	LD	I _O = 0.5 mA			0.4	V
Low-level output voltage2	V _O L2	SDA(DI), PORT1 to 3	I _O = 3.0 mA			0.4	V
Output off leak current	I OFF	LD, PORT1 to 3	V _O = 3.0 V			1	μA
CP Output off leak current	I OFCP	СР	V _O = 1.5 V			100	nA
CP output current	Icp	СР	V _O = 1.5 V		±6.5		mA
High-level input current1	IH1	SCL(CL), SDA(DI), CE, PS, RST, BUSSW	Vi = 3.0 V			5	μА
High-level input current2	IH2	XIN			3		μΑ
Low-level input current1	IL1	SCL(CL), SDA(DI), CE, PS, RST, BUSSW	Vi = 0 V			5	μА
Low-level input current2	IL2	XIN			3		μA
Supply current	Icco	V _{CC} + VCP	*1		7.0		mA
Standby current	Isb	No signal input	Power saving mode		0.4		mA

Note: *PI = 2000 MHz, Vpi = 0 dBm, RI = 19.2 MHz, Vri = 0 dBm Other input pins = 0 V, I/O pins = open, CP off, output pins = high

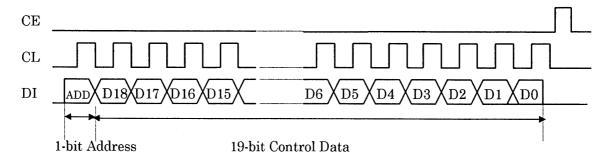
LV2151V

Pin Descriptions

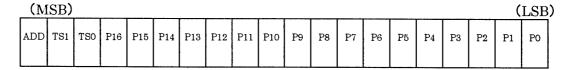
Pin	Symbol	I/O	Description
1	XIN	CMOS input	Crystal oscillator connection pins.
20	XOUT	Civios iriput	Crystal oscillator conflection pins.
			Power saving switch.
2	PS	CMOS input with a pull-down resistor built in.	"Open or Low": Power saving mode
			"High": Active mode
3	V _{SS}		Ground pin for logic system
4	CP-GND		Ground pin for charge pump. (Fixed current output)
5	CP	BIP output	Charge pump output. (Fixed current output)
6	VCP		V _{CC} supply for charge pump.
7	V _{CC}		V _{CC} supply. (Except charge pump circuit)
8	GND		Ground pin for RF block.
			Reset pin for I ² C bus.
9	RST	CMOS input with a pull-up resistor built in.	Connect capacitor to GND.
9	KST	Civios iriput with a pull-up resistor built iii.	"Open or High" Release
			"Low" Reset
10	PI	Bipolar input	Comparator signal input. VCO output must be AC coupled to input.
			Serial data select input.
11	BUSSW	CMOS input with a pull-up resistor built in.	"Open or High" I ² C bus
			"Low" 3-wire bus
12	SCL(CL)		Data input pins
13	SDA(DI)	CMOS input	
14	CE		CE is used as an address selector pin if I ² C bus is used.
15	LD		PLL unlock detector output pin.
16	PORT1	NPN transistor open collector output	
17	PORT2	ive iv transistor open collector output	Output port pins for band switch.
18	PORT3		
19	BUF	Bipolar output	Buffer output pin for crystal oscillator.

Data Format

(1) 3-Wire Bus (BUSSW pin set low.)



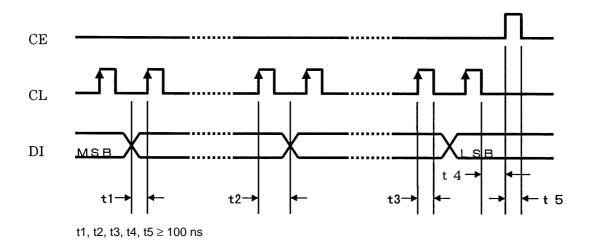
Programmable Counter and Test Mode
 ADD latch address data must be set to 1.



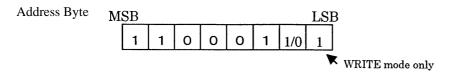
2. Reference Counter and Other Control ADD latch address data must be set to 0

(M	SB)																	(L	SB)	
ADD	CPD	ULD	UE1	UEO	PORT	PORT	PORT	R11	R10	R9	R8	R7	R6	R5	R4	R3	R2	R1	RO	
					3	2	1													

Serial Data Timing

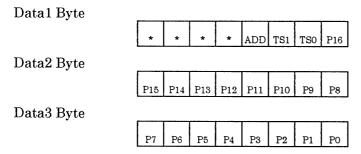


(2) I2C bus BUSSW pin set open or high.

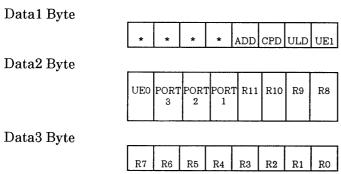


CE pin is high when the data is set to 1. CE pin is low when the data is set to 0.

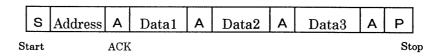
1. Programmable Counter and Testing Mode



2. Reference Counter and Other Control



Receiving Data Diagrams



Serial Data Description

(1) Programmable Counter and Test Mode

Bit "ADD(Latch Address Data)" = 1

(M	SB)																	(LSB
ADD	TS1	TS0	P16	P15	P14	P13	P12	P11	P10	P9	P8	P7	P6	P5	P4	РЗ	P2	P1	P0

1. Programmable Counter

Bits P0 to P16 determine programmable divider ratios. Binary value with P0 as the LSB.

The division ratio can be set in the range of 4032 to 131071.

Ex. Settable division ratio factor is 8192

ADD	TS1	TS0	P16	P15	P14	P13	P12	P11	P10	P9	P8	P7	P6	P5	P4	Рз	P2	P1	P0
1	0	0	0	0	0	1	0	0	0	0	0	0	0	0	0	0	0	0	0

2. Test Mode

TS0 and TS1 are testing bits. These bits must normally be set to 0.

(2) Reference Counter and Other Control

ADD is the latch address bit. This bit must be set to 0.

(N	ISB)																	(L	SB)
ADD	CPD	ULD	UE1	UE0	PORT 3	PORT 2	PORT 1	R11	R10	R9	R8	R7	R6	R5	R4	R3	R2	R1	RO

1. Reference Counter

Bits R0 to R11 determine programmable divider ratios. Binary value with R0 as the LSB.

The division ratio can be set in the range of 20 to 4095.

Ex. Settable division ratio factor is 2048 ("*" = Don't care)

							[
ADD	CPD	ULD	UE1	UE0	PORT	PORT	PORT	R11	R10	R9	R8	R7	R6	R5	R4	R3	R2	R1	RO
0	*	*	*	*	*	*	*	1	0	0	0	0	0	0	0	0	0	0	0

2. Phase Comparator Output Control

Bit CPD is phase comparator polarity switching data.

CPD	Phase comparator polarity
0	(1) Shown Fig.1
1	(2) Shown Fig.1

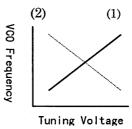


Fig.1

3. Unlock Detection Control

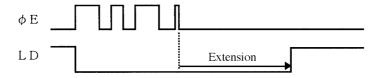
ULD is used to control the signal length which determines whether or not the PLL is locked. PLL is determined as unlocked if a phase error signal longer than that in the table below is detected.

ULD	Thresholds	fXIN = 10.24 MHz
0	±4/fXIN	390 ns
1	±8/fXIN	780 ns

4. Unlock Output Signal Extension Control

UE0 and UE1 are used to control the extension of LD signal detected in the unlock detector circuit.

UE1	UE0	Extension Time	fref = 50 k
0	0	4*(1/fref)	80 µs
0	1	8*(1/fref)	160 µs
1	0	16*(1/fref)	320 µs
1	1	32*(1/fref)	640 µs

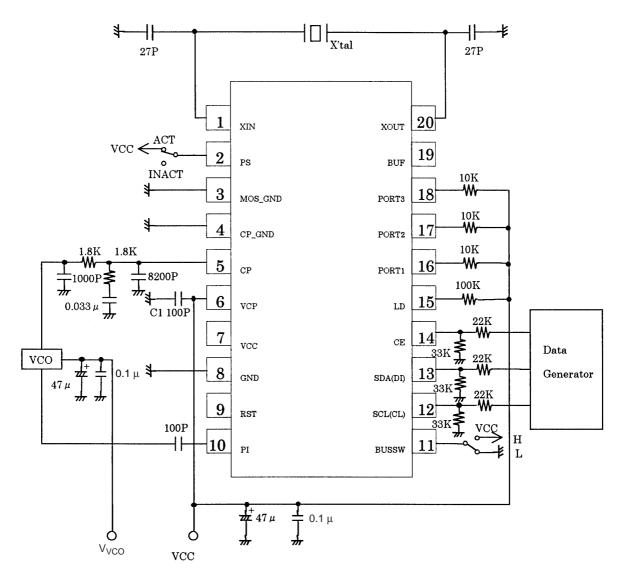


5. Band Switching Output Ports

PORT1 to PORT3 are used to switch the outputs for pin16 to pin18, respectively. The pins go to high when the data is set to 0, and go to low when set to 1.

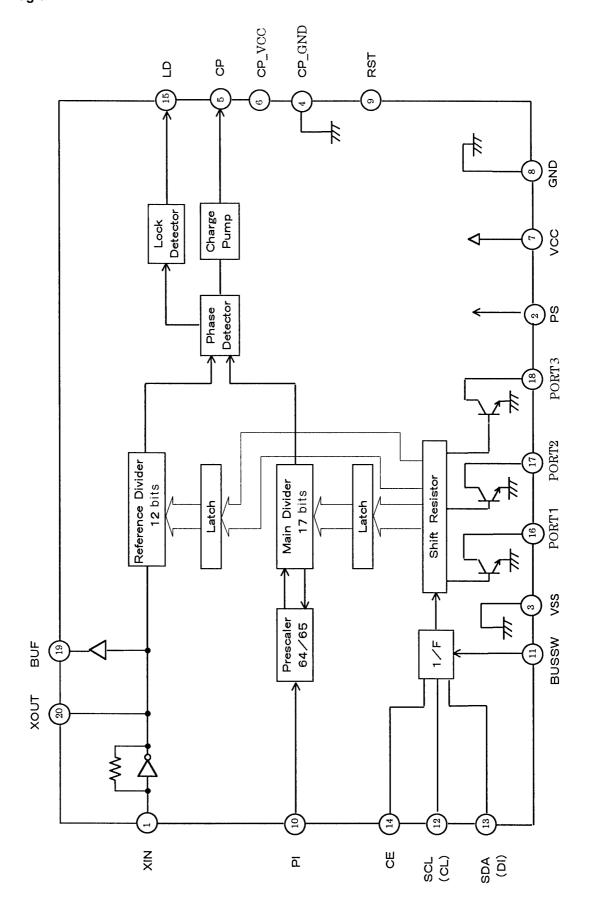
PORT*	RT* Output	
0	High	
1	Low	

LV2151V Evaluation Circuit



Unit (resistance: Ω , capacitance:F)

Block Diagram



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